



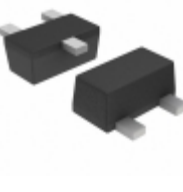
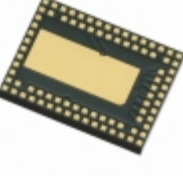


	<h2>SI1032X-T1-E3</h2>
	<p>Hersteller-Teilenummer: SI1032X-T1-E3</p> <p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p> <p>Teil der Beschreibung: MOSFET N-CH 20V 200MA SC89-3</p> <p>Datenblätter:  SI1032X-T1-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 284683 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI1032X-T1-E3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET N-CH 20V 200MA SC89-3
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	284683 pcs Stock
detaillierte Beschreibung	N-Channel 20V 200mA (Ta) 300mW (Ta) Surface
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	SC-89, SOT-490
Supplier Device-Gehäuse	SC-89-3
Verlustleistung (max)	300mW (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	200mA (Ta)
Rds On (Max) @ Id, Vgs	5 Ohm @ 200mA, 4.5V
VGS (th) (Max) @ Id	1.2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	0.75nC @ 4.5V
Antriebsspannung (Max Rds On, Min Rds On)	1.5V, 4.5V
Vgs (Max)	±6V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SI1032X-T1-E3TR


SI1032X-T1-E3 ist neu im Original, Suche SI1032X-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI1032X-T1-E3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI1032X-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI1033-A-GM Energy Micro (Silicon Labs) IC RF TXRX+MCU ISM<1GHZ 85-VFLGA</p>	 <p>SI1032R-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 20V 140MA SC-75A</p>	 <p>SI1032R-T1-GE3 Vishay / Siliconix MOSFET N-CH 20V 140MA SC-75A</p>	 <p>SI1032X-T1-GE3 Vishay / Siliconix MOSFET N-CH 20V 200MA SC89-3</p>
 <p>SI1032X-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 20V 200MA SC89-3</p>	 <p>SI1033-B-GM3 Energy Micro (Silicon Labs) IC RF TXRX+MCU ISM<1GHZ 85-VFLGA</p>	 <p>SI1032X-T1-E3 Vishay / Siliconix MOSFET N-CH 20V 200MA SC89-3</p>	 <p>SI1033-A-GMR Energy Micro (Silicon Labs) IC RF TXRX+MCU ISM<1GHZ 85-VFLGA</p>

heiße Teile

Mehr

 SI1026X-T1	 SI1026X-T1-E3	 SI1026X-T1-E3	 SI1026X-T1-GE3	 SI1026X-T1-GE3
 SI1028X-T1-GE3	 SI1028X-T1-GE3	 SI1029X-T1-GE3	 SI1029X-T1-GE3	 SI1031R-T1
 SI1031R-T1-E3	 SI1031R-T1-E3	 SI1031R-T1-GE3	 SI1031R-T1-GE3	 SI1031X-T1
 SI1031X-T1-E3	 SI1031X-T1-E3	 SI1031X-T1-GE3	 SI1031X-T1-GE3	 SI1032R-T1
 SI1032R-T1-E3	 SI1032R-T1-E3	 SI1032R-T1-GE3	 SI1032R-T1-GE3	 SI1032X-T1
 SI1032X-T1-E3	 SI1032X-T1-GE3	 SI1032X-T1-GE3	 SI1033X-T1	 SI1033X-T1-E3
 SI1033X-T1-E3	 SI1034CX-T1-GE3	 SI1034CX-T1-GE3	 SI1034X-T1	 SI1034X-T1-E3
 SI1034X-T1-E3	 SI1034X-T1-GE3	 SI1034X-T1-GE3	 SI1035X-T1	 SI1035X-T1-E3
 SI1035X-T1-E3	 SI1035X-T1-GE3	 SI1035X-T1-GE3	 SI1039X-T1-E3	 SI1039X-T1-E3
 SI1040X-T1-E3	 SI1040X-T1-E3	 SI1040X-T1-GE3	 SI1040X-T1-GE3	 SI1041ADY

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